

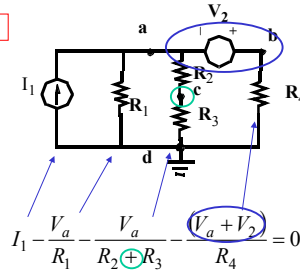
Calbot Contest Monday 5/12



Jason Gatt and Kevin Ha
"Best in Show" in
Turbot/Calbot
Contest F00

EXAMPLE WITH BOTH SPECIAL CASES

Lecture 8



$$I_1 - \frac{V_a}{R_1} - \frac{V_a}{R_2 + R_3} - \frac{V_a + V_2}{R_4} = 0$$

Lecture Review

Review of Basic Circuit Concepts

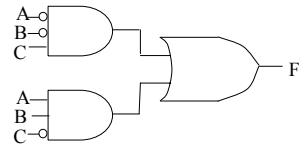
Sheila Ross

- Circuit Analysis
- Transients
- Logic
- Timing Diagrams
- Dependent Sources and Op-Amps
- Load Line and V_{OUT} VS V_{IN}
- Diodes
- MOS Operation

How to Combine Gate to Produce a Desired Logic Function?
(More basic Logical Synthesis)

Example:

A	B	C	F
0	0	0	0
0	0	1	1
0	1	0	0
0	1	1	0
1	0	0	0
1	0	1	0
1	1	0	1
1	1	1	0

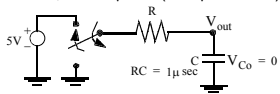


$$F = \bar{A} \bar{B} C + A B \bar{C}$$

Lecture 7

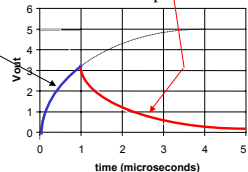
PULSE: Output is Rising exponential then Falling exponential

Example: Switch rises at $t=0$, falls at $t = 0.1, 1$ or $10\mu\text{sec}$ (Do $1\mu\text{sec}$ case)



Now starting at $1\mu\text{sec}$ we are discharging the capacitor so the form is a falling exponential with initial value 3.16 V:

What is equation?



Solution: for $RC = 1\mu\text{sec}$: during the first rise V obeys:

$$V = 5[1 - e^{-\frac{t}{10^{-6}}}]$$

Thus at $t = 1\mu\text{sec}$, rising voltage reaches

$$5[1 - e^{-1}] = 3.16V$$

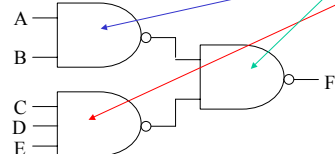
Logical Synthesis
Guided by DeMorgan's Theorem

DeMorgan's Theorem :

$$A + B + C = \overline{[\bar{A} \bar{B} \bar{C}]} \quad \text{or} \quad \bar{A} + \bar{B} + \bar{C} = \overline{[A B C]}$$

Example of Using DeMorgan's Theorem:

$$F = A \cdot B + C \cdot D \cdot E = \overline{[\bar{A} \bar{B}] \cdot \overline{[C D E]}}$$



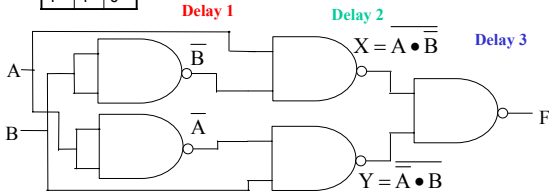
Thus any sum of products expression can be immediately synthesized from NAND gates alone

Logical Synthesis of XOR

A	B	F
0	0	0
0	1	1
1	0	1
1	1	0

$$F = A \cdot \bar{B} + \bar{A} \cdot B$$

We Need a Timing Diagram!



The 4 Basic Linear Dependent Sources

Lecture 13

Constant of proportionality

Parameter being sensed

Output

Voltage-controlled voltage source ... $V = A_v V_{cd}$

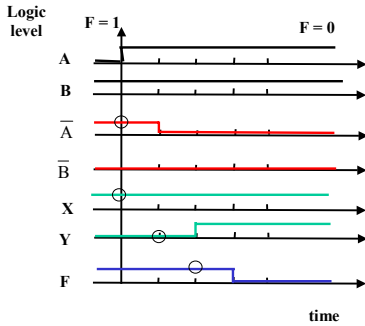
Current-controlled voltage source ... $V = R_m I_c$

Current-controlled current source ... $I = A_i I_c$

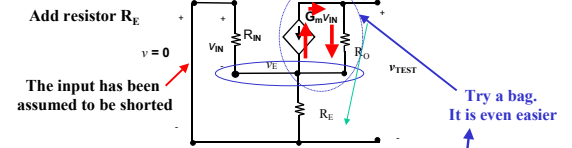
Voltage-controlled current source ... $I = G_m V_{cd}$



Timing Diagram for Delays in Logic



EXAMPLE CIRCUIT: INCREASED OUTPUT RESISTANCE



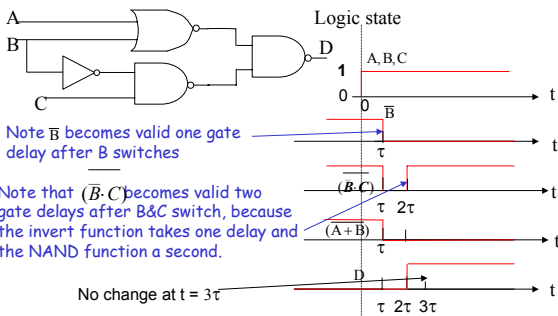
Analysis: apply i_{TEST} and evaluate v_{TEST}

Unknowns: i_{TEST} , v_{TEST} , v_{IN} , v_E
Need 3 equations to find the ratio of i_{TEST} / v_{TEST}
 $v_{IN} = -v_E$ and is not zero!
KVL at v_E
KVL at v_{OUT}

Intuitive Explanation: $G_m V_{IN}$ burps current which has to also go through R_O . This raises v_{TEST} and the output impedance v_{TEST} / i_{TEST}
Try a bag. It is even easier.
Finish this in the homework

TIMING DIAGRAMS

Show transitions of variables vs time

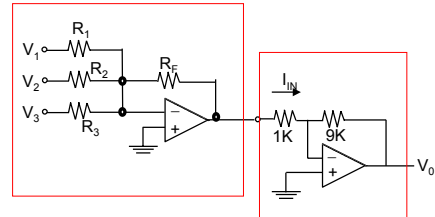


Note \bar{B} becomes valid one gate delay after B switches

Note that $(\bar{B} \cdot C)$ becomes valid two gate delays after B&C switch, because the invert function takes one delay and the NAND function a second.

No change at $t = 3\tau$

CASCADE OP-AMP CIRCUITS



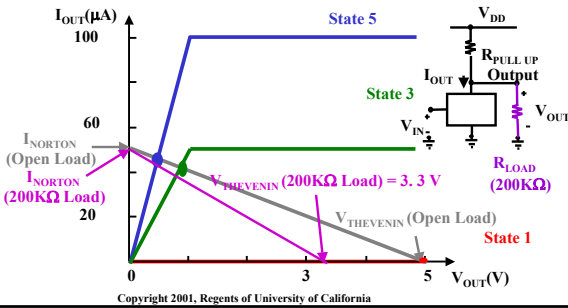
How do you get started on finding V_0 ?

Hint: Identify Stages

Hint: I_{IN} does not affect V_{O1}

See the further examples of op-amp circuits in the reader

Composite Current Plot for the 42PD Circuit with 200kΩ Load to Ground

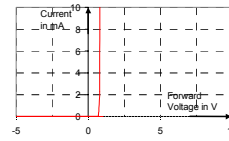


DIODE I-V CHARACTERISTICS AND MODELS

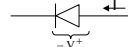
The equation $I = I_0 \exp(qV/kT - 1)$ is graphed below for $I_0 = 10^{-15}$ A

Simple "Perfect Rectifier" Model

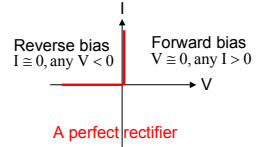
If we can ignore the small forward-bias voltage drop of a diode, a simple effective model is the "perfect rectifier," whose I-V characteristic is given below:



The characteristic is described as a "rectifier" – that is, a device that permits current to pass in only one direction. (The hydraulic analog is a "check valve".) Hence the symbol:

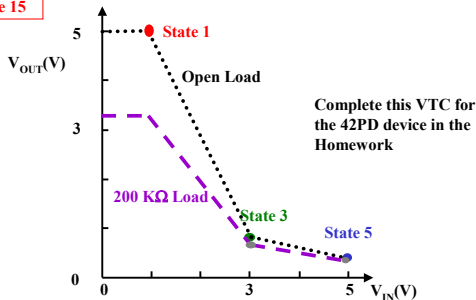


Copyright 2001, Regents of University of California

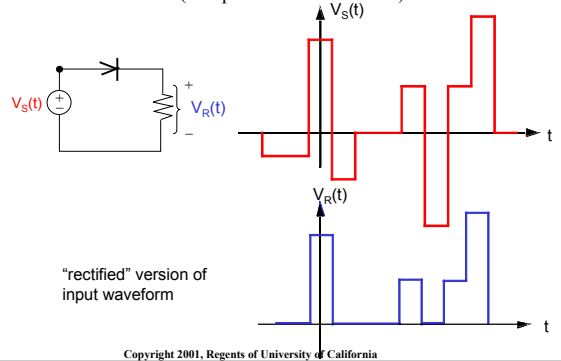


Voltage Transfer Function for the 42PD Logic Circuit w/o Load

Lecture 15

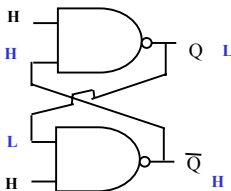


COOL THINGS A DIODE CAN DO (Use perfect rectifier model)



Feedback Can Provide Memory

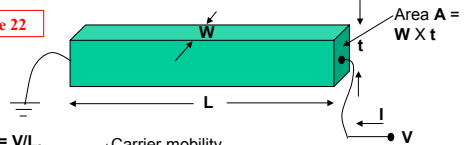
Lecture 19



Copyright 2001, Regents of University of California

Physics of Current Flow, Resistance, Resistivity

Lecture 22



$E = V/L$
 $I = V/R$
 $R = \rho L/A = (1/q \mu N) L/W t = (L/W) / \mu(qNt)$

But $q N t$ has the dimensions of charge per unit area and represents the charge per unit area in a film of thickness t when the film has N carriers/cm³ and is t units thick. Thus we call $q N t$ the "Q" and

$R = (L/W) / \mu Q = L/W R_{\square}$

Where R_{\square} is the resistance of a "square" of the film. Clearly if L is four times W , then $R = 4 R_{\square}$.

Copyright 2001, Regents of University of California

Relation of Current to Physical Parameters

$$I_D = \mu_n C_{ox} \left(\frac{W}{L} \right)_n (V_{GS} - V_T) \cdot V_{OUT-SAT-n}$$

Mobility of carriers \nearrow \nearrow \nearrow \nearrow \nearrow
 Oxide thickness \nearrow \nearrow \nearrow \nearrow \nearrow
 Geometrical Layout \nearrow \nearrow \nearrow \nearrow \nearrow
 Excess Gate drive \nearrow \nearrow \nearrow \nearrow \nearrow
 Voltage of scattering velocity limit \nearrow \nearrow \nearrow \nearrow \nearrow

$$\mu_n = 500 \text{ (cm}^2 / \text{Vs)} \quad \mu_p = 150 \text{ (cm}^2 / \text{Vs)}$$

$$C_{ox} = \frac{\epsilon_{ox}}{t_{ox}} = \frac{(8.85 \times 10^{-14} \text{ F/cm})(3.9)}{6 \times 10^{-7} \text{ cm}} = 5.75 \times 10^{-7} \text{ F/cm}^2$$

$$V_{OUT-SAT-n} = E_{Crit} \cdot L = 10^4 \text{ (V/cm)} \cdot 0.25 \times 10^{-4} \text{ cm} = 0.25 \text{ V}$$